

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _A = +25°C
-600V	13Ω @ V _{GS} = -10V	-0.25A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Motor Control
- Backlighting
- AC-DC Converters

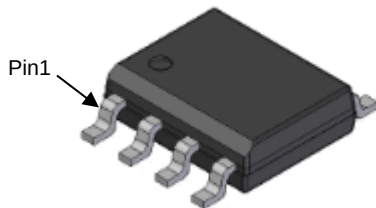
Features and Benefits

- Low On-Resistance
 - High BV_{DSS} Rating for Power Application
 - Low Input Capacitance
 - Fast Switching
 - High Efficiency
 - **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
 - **Halogen and Antimony Free. "Green" Device (Note 3)**
 - For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative.
- <https://www.diodes.com/quality/product-definitions/>

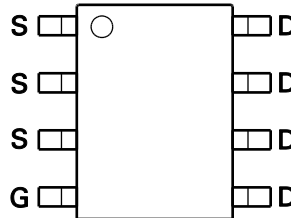
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe.
Solderable per MIL-STD-202, Method 208 
- Weight: 0.076 grams (Approximate)

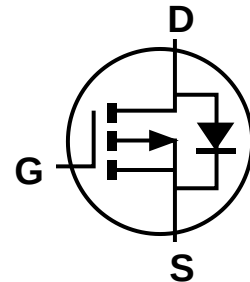
SO-8 (Standard B)



Top View



Pin-Out
Top View



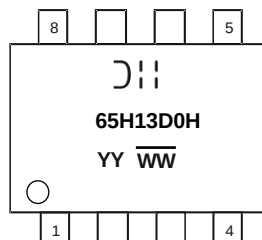
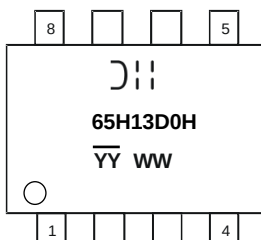
Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP65H13D0HSS-13	SO-8 (Standard B)	4,000 / Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



 = Manufacturer's Marking
 65H13D0H = Product Type Marking Code
 YYWW or YYWW = Date Code Marking
 YY or YY = Year (ex: 21 = 2021)
 WW or WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage (Note 5)	V _{DSS}	-600	V
Gate-Source Voltage	V _{GSS}	±30	V
Continuous Drain Current (Note 6) V _{GS} = -10V	I _D	-0.25 -0.20	A
Maximum Body Diode Forward Current (Note 6)	I _S	-0.25 -0.20	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-2	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)	I _{SM}	-2	A
Peak Diode Recovery dv/dt (Note 8)	dv/dt	5	V/ns

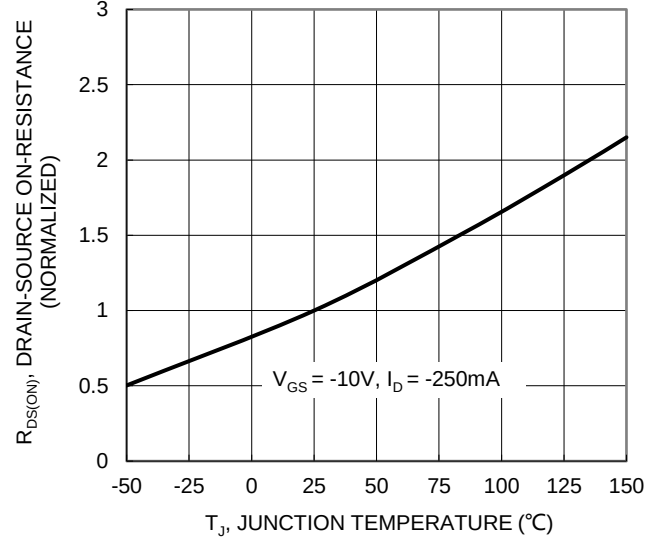
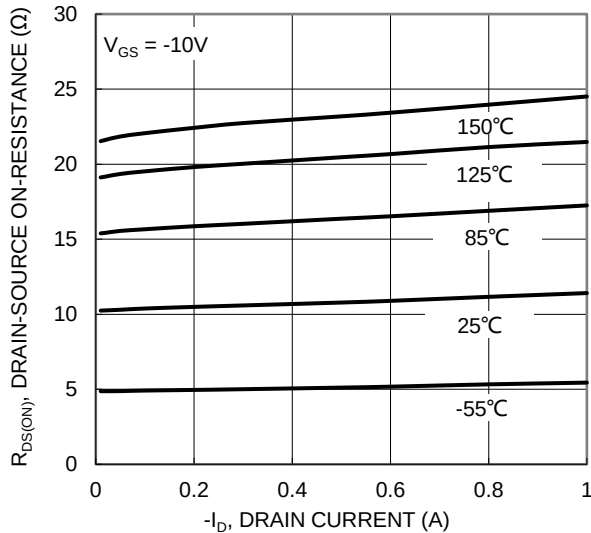
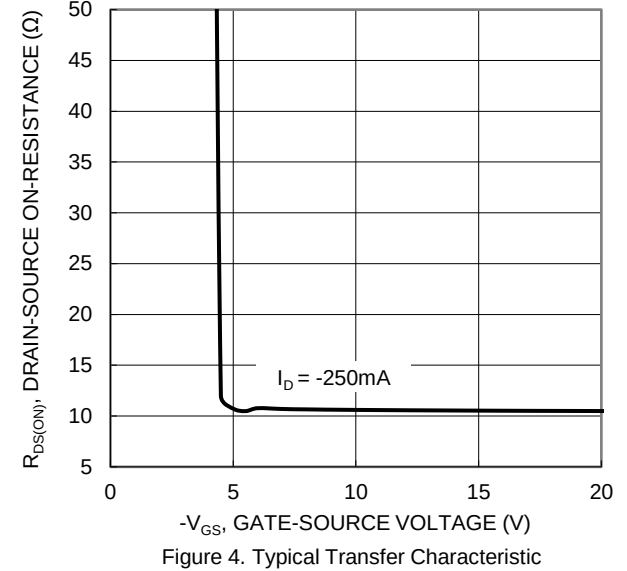
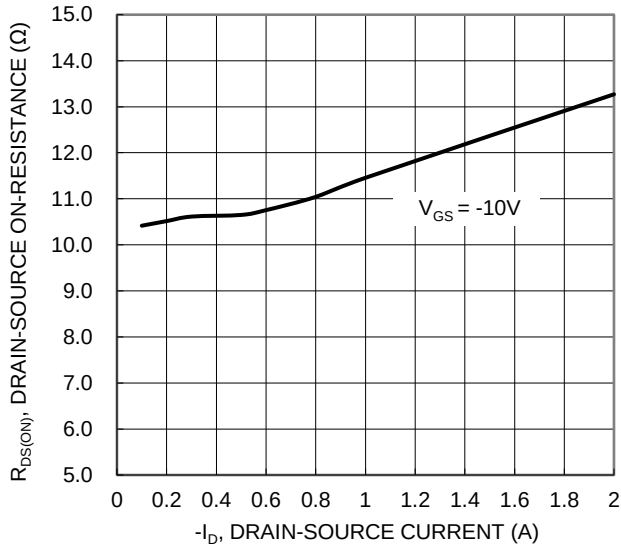
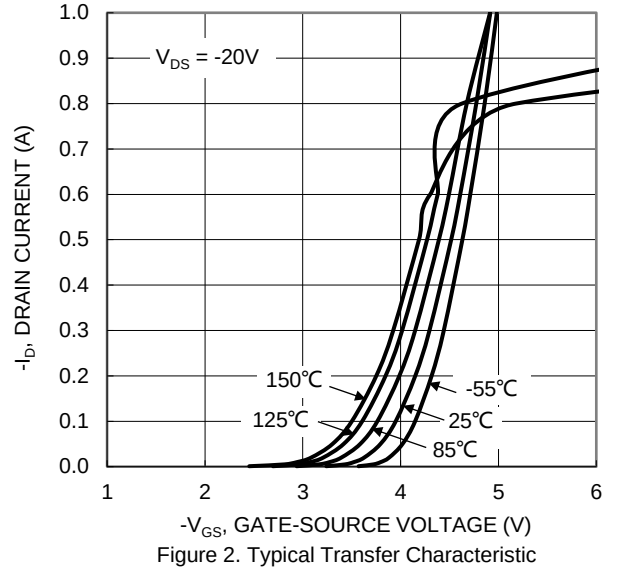
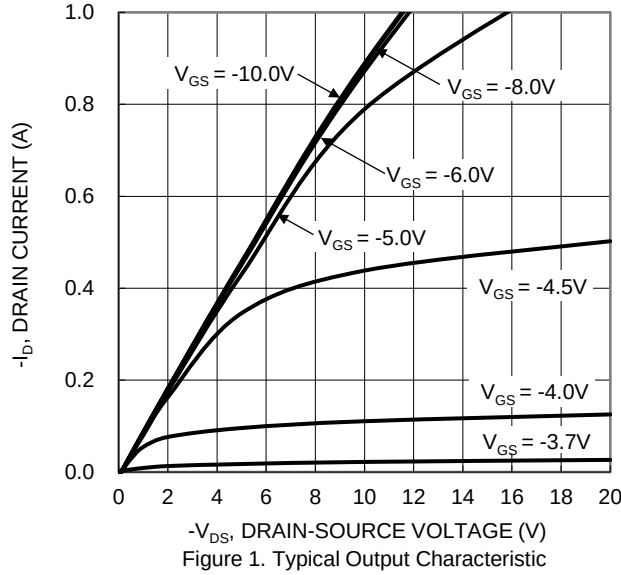
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

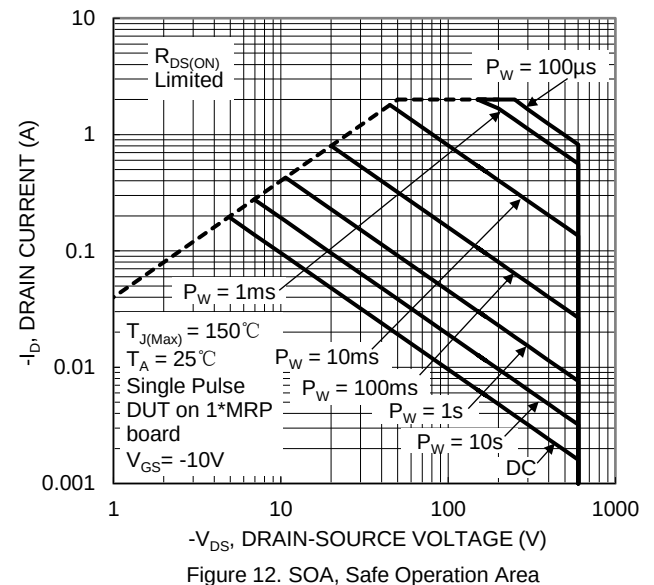
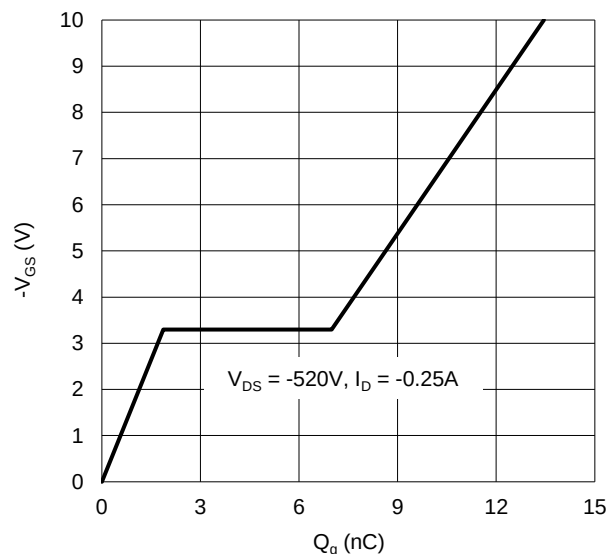
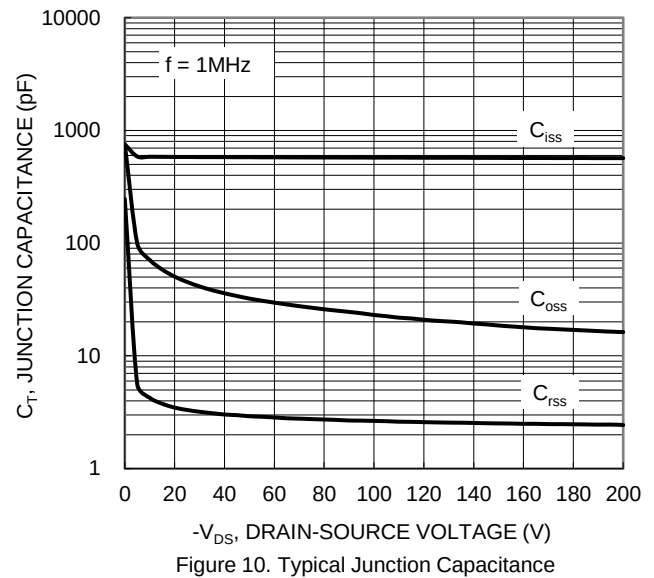
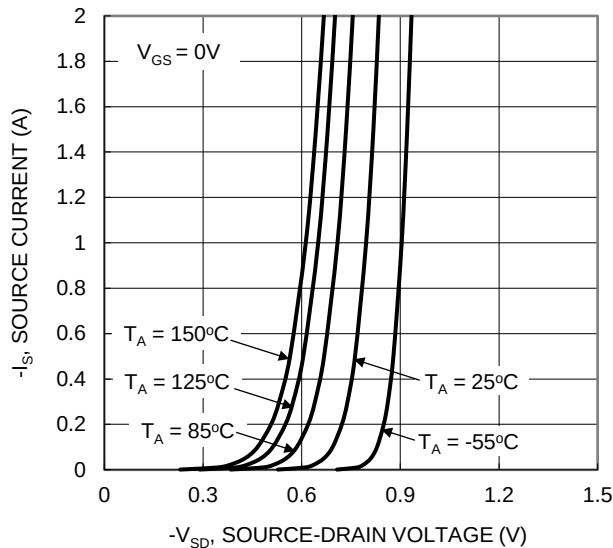
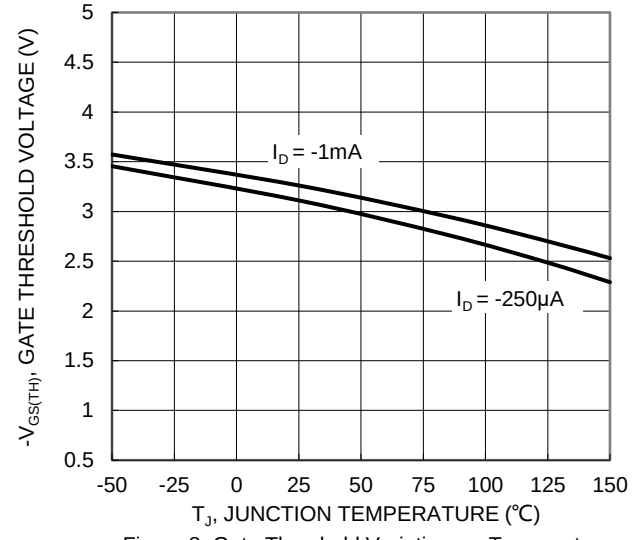
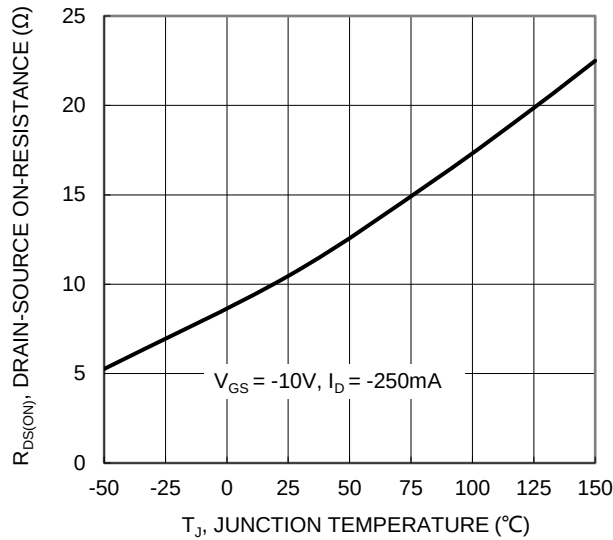
Characteristic	Symbol	Value	Unit
Power Dissipation, @T _A = +25°C (Note 6)	P _D	1.9	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	R _{θJA}	65	°C/W
Power Dissipation, @T _A = +25°C (Note 7)	P _D	1.25	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7)	R _{θJA}	100	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV _{DSS}	-650	—	—	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	µA	V _{DS} = -650V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	100	nA	V _{GS} = ±30V, V _{DS} = 0V
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V _{GS(TH)}	-2	-3	-4	V	V _{DS} = V _{GS} , I _D = -250µA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	10.5	13	Ω	V _{GS} = -10V, I _D = -0.25A
Diode Forward Voltage	V _{SD}	—	-0.7	-1.3	V	V _{GS} = 0V, I _S = -0.25A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	—	582	—	pF	V _{DS} = -25V, f = 1MHz, V _{GS} = 0V
Output Capacitance	C _{oss}	—	45	—		
Reverse Transfer Capacitance	C _{rss}	—	3.3	—		
Gate Resistance	R _g	—	12.7	—	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge	Q _g	—	13.4	—	nC	V _{DD} = -520V, I _D = -0.25A, V _{GS} = -10V
Gate-Source Charge	Q _{gs}	—	2	—		
Gate-Drain Charge	Q _{gd}	—	4.9	—		
Turn-On Delay Time	t _{d(ON)}	—	16	—	ns	V _{DD} = -325V, V _{GS} = -10V, R _G = 3Ω, I _D = -0.25A
Turn-On Rise Time	t _r	—	10	—		
Turn-Off Delay Time	t _{d(OFF)}	—	44	—		
Turn-Off Fall Time	t _f	—	85	—		
Body Diode Reverse Recovery Time	t _{RR}	—	160	—	ns	I _S = -1A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}	—	1	—	µC	

- Notes:
5. HTRB V_{DS} maximum is -480V.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square pad layout.
 7. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 8. Guaranteed by design. Not subject to production testing.
 9. Short duration pulse test used to minimize self-heating effect.





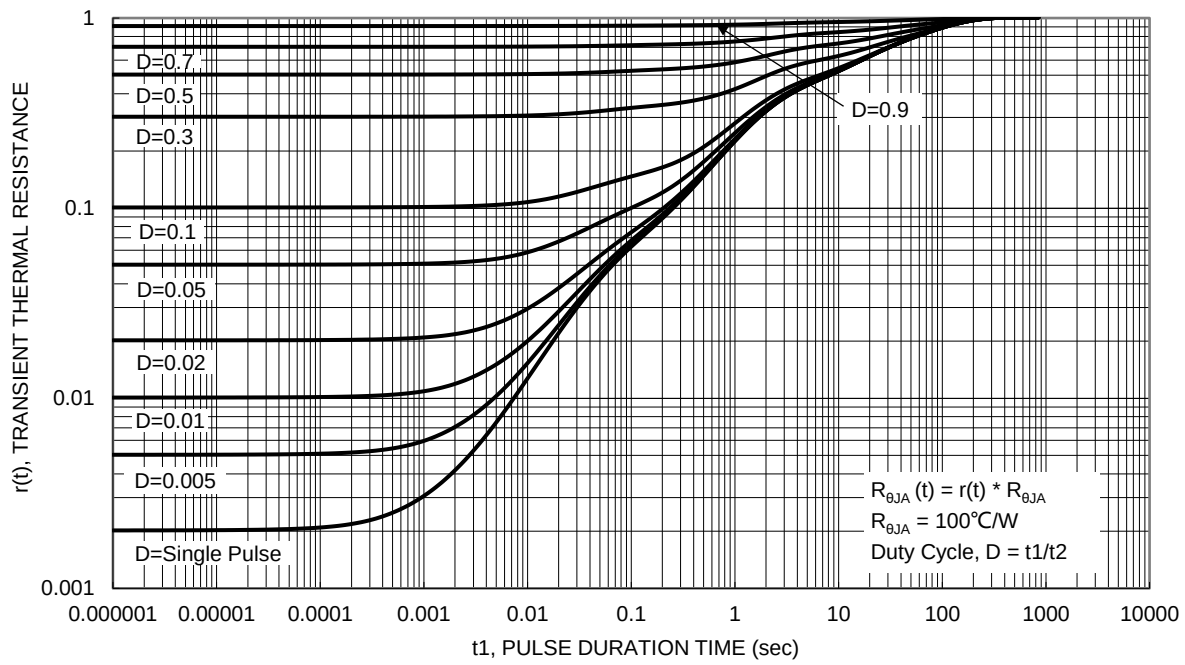
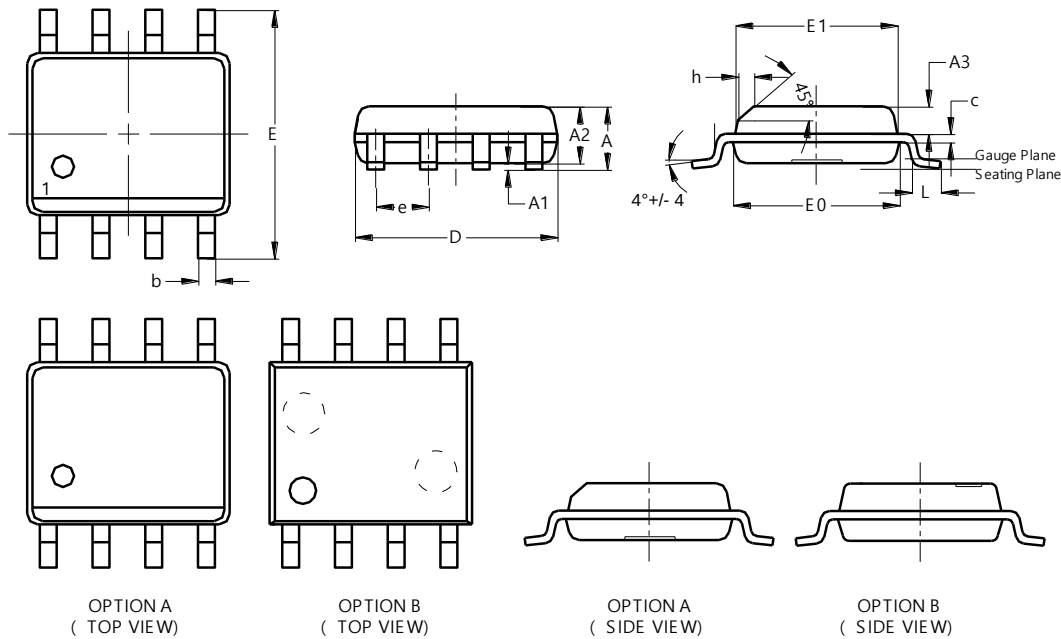


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

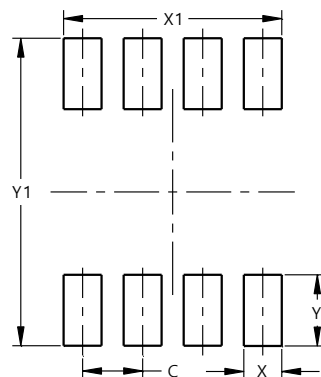
SO-8 (Standard B)



Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SO-8 (Standard B)



Dimensions	Value (in mm)
C	1.27
X	0.802
X1	4.612
Y	1.505
Y1	6.50

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